### **MRF316**



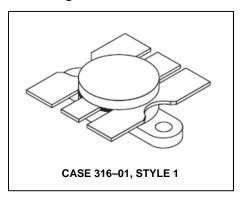
### The RF Line NPN Silicon Power Transistor 80W, 3.0-200MHz, 28V

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Designed primarily for wideband large-signal output amplifier stages in the 30-200 MHz frequency range.

- Guaranteed performance at 150 MHz, 28 Vdc Output power = 80 W Minimum gain = 10 dB
- Built-in matching network for broadband operation
- 100% tested for load mismatch at all phase angles with 30:1 VSWR
- Gold metallization system for high reliability applications

#### **Product Image**



#### MAXIMUM RATINGS

Rating	Symbol	Unit		
Collector–Emitter Voltage	V <sub>CEO</sub>	Vdc		
Collector-Base Voltage	V <sub>CBO</sub>	CBO 65		
Emitter–Base Voltage	V <sub>EBO</sub>	4.0	Vdc	
Collector Current — Continuous Peak	I <sub>C</sub>	9.0 13.5	Adc	
Total Device Dissipation @ T <sub>C</sub> = 25°C (1) Derate above 25°C	P <sub>D</sub>	220 1.26	Watts W/°C	
Storage Temperature Range	T <sub>stg</sub> -65 to +150		°C	

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R <sub>eJC</sub>	0.8	°C/W

#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•	•		•	
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 50 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	35	_	_	Vdc
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 50 mAdc, V <sub>BE</sub> = 0)	V <sub>(BR)CES</sub>	65	_	_	Vdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = 50 mAdc, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	65	_	_	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 5.0 mAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	4.0	_	_	Vdc
Collector Cutoff Current (V <sub>CB</sub> = 30 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	_	_	5.0	mAdc

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#### ON CHARACTERISTICS

DC Current Gain (I <sub>C</sub> = 4.0 Adc, V <sub>CE</sub> = 5.0 Vdc)	h <sub>FE</sub>	10	_	80	_
DYNAMIC CHARACTERISTICS	•				
Output Capacitance (V <sub>CB</sub> = 28 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>ob</sub>	_	100	130	pF

NOTE: (continued)

1. This device is designed for RF operation. The total device dissipation rating applies only when the device is operated as an RF amplifier.

### **ELECTRICAL CHARACTERISTICS** — **continued** $(T_C = 25^{\circ}C)$ unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
NARROW BAND FUNCTIONAL TESTS (Figure 1)					
Common–Emitter Amplifier Power Gain (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 80 W, f = 150 MHz)	G <sub>PE</sub>	10	13	_	dB
Collector Efficiency (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 80 W, f = 150 MHz)	η	55	_	_	%
Load Mismatch (V <sub>CC</sub> = 28 Vdc, P <sub>out</sub> = 80 W CW, f = 150 MHz, VSWR = 30:1 all phase angles)	Ψ	No Degradation in Output Power			

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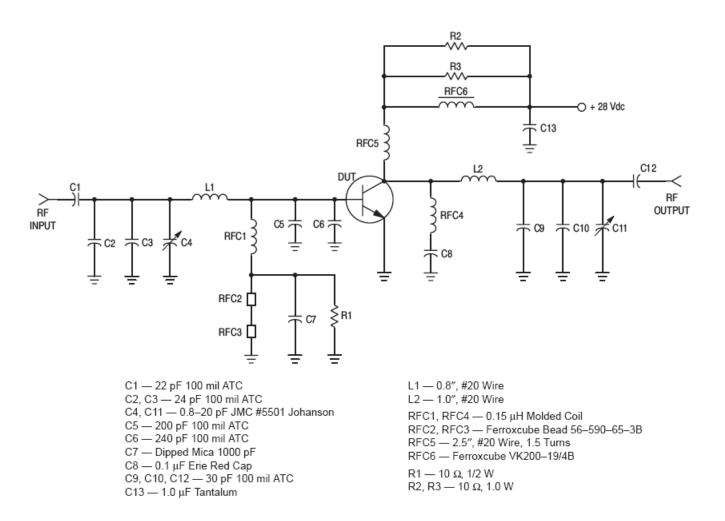


Figure 1. 150 MHz Test Amplifier

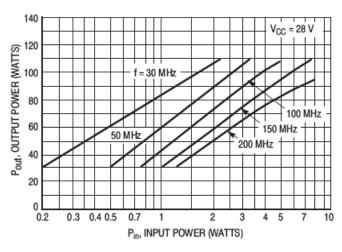
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#### TYPICAL PERFORMANCE CURVES



Pout = 80 W VCC = 28 V VCC = 28 V

Figure 2. Output Power versus Input Power

Figure 3. Power Gain versus Frequency

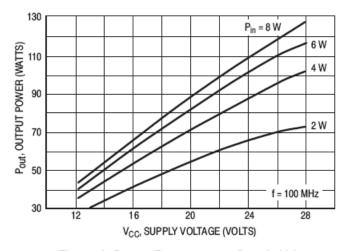


Figure 4. Output Power versus Supply Voltage

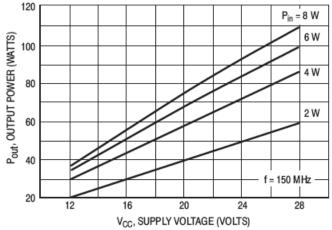


Figure 5. Output Power versus Supply Voltage

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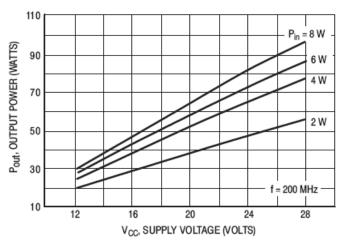
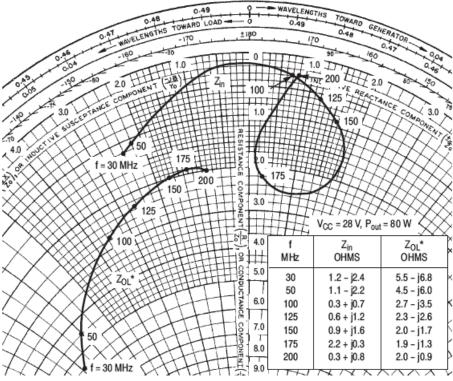


Figure 6. Output Power versus Supply Voltage



 $Z_{OL}^*$  = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

Figure 7. Series Equivalent Input-Output Impedance

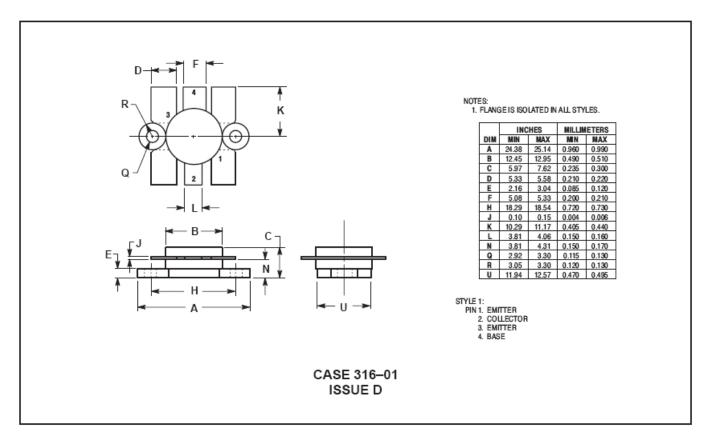
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#### PACKAGE DIMENSIONS



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